

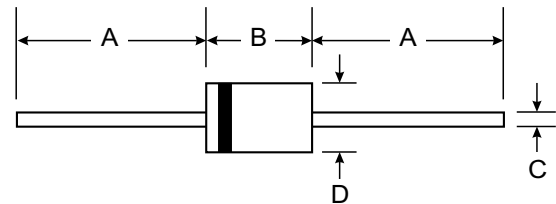
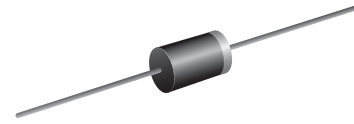
VOLTAGE RANGE: 30- 100V
CURRENT: 12 A

Features

- Metal of silicon rectifier , majority carrier conduction
- Guard ring for transient protection
- Low power loss,high efficiency
- High current capability,low VF
- High surge capacity

Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-201AD		
Dim	Min	Max
A	25.40	—
B	7.20	9.50
C	1.20	1.30
D	4.80	5.30
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	12SQ030	12SQ035	12SQ040	12SQ045	12SQ050	12SQ060	12SQ080	12SQ100	Unit	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	30	35	40	45	50	60	80	100	V	
Maximum RMS Voltage	V_{RMS}	21	24.5	28	31.5	35	42	56	70	V	
Maximum DC Blocking Voltage	V_{DC}	30	35	40	45	50	60	80	100	V	
Maximum Average Forward Rectified Current @ $T_c=95^\circ\text{C}$	$I_{(AV)}$	12								A	
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load(JEDEC Method)	I_{FSM}	275								A	
Peak Forward Voltage at 12A DC(Note1)	V_F	0.55			0.7		0.8			V	
Maximum DC Reverse Current @ $T_j=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_j=100^\circ\text{C}$	I_R	0.5					50				mA
Typical Junction Capacitance (Note2)	C_J	450									pF
Typical Thermal Resistance (Note3)	R_{JC}	3.0									$^\circ\text{C}/\text{w}$
Operating Temperature Range	T_J	-55 to+200									$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to+200									$^\circ\text{C}$

NOTES:1.300us Pulse Width, 2%Duty Cycle.

2.Measured at 1.0 MHZ and applied reverse voltage of 4.0VDC.

3.Thermal Resistance Junction to case.

FIG.1-FORWARD CURRENT DERATING CURVE

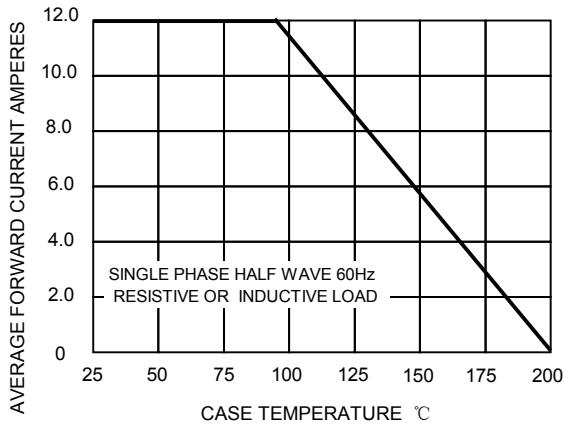


FIG.2-MAXIMUM NON-REPETITIVE SURGE

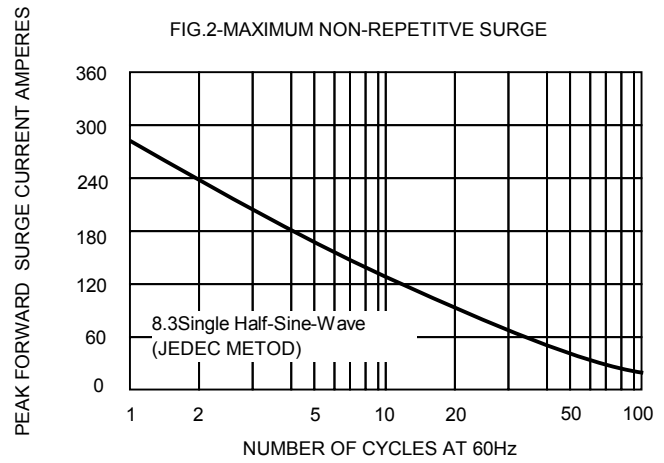


FIG.3-TYPICAL REVER CHARACTERISTICS

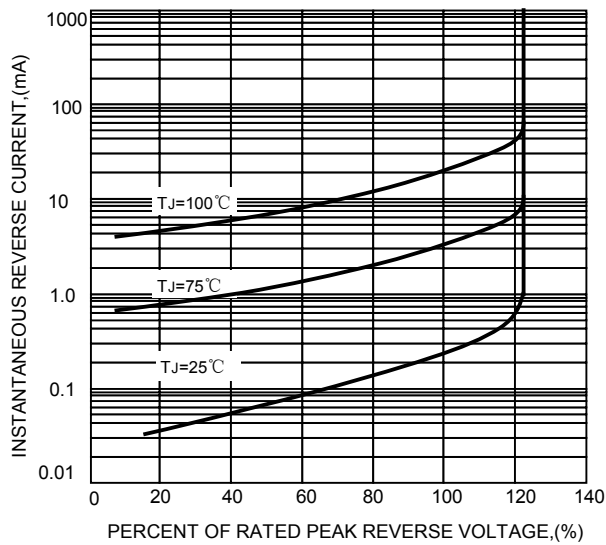


FIG.4-TYPICAL FORWARD CHARACTERISTICS

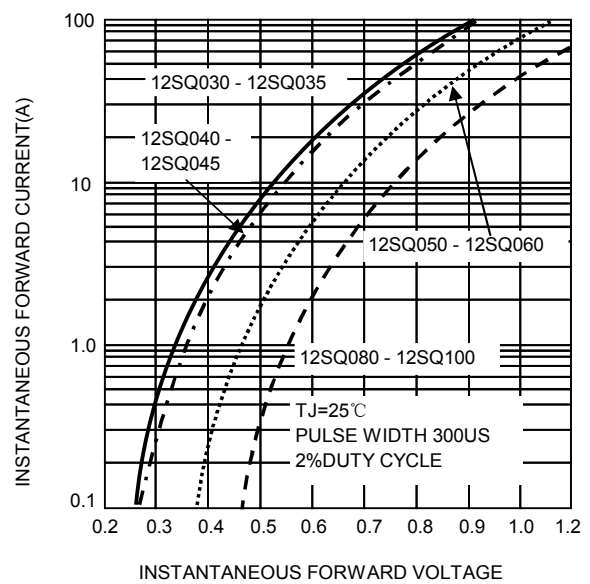


FIG.5-TYPICAL JUNCTION CAPACITANCE

